

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- High current capability
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

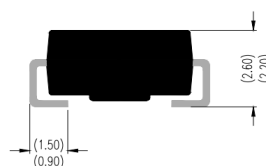
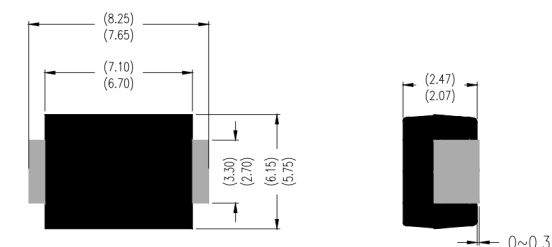
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

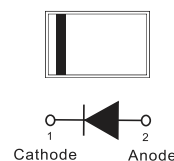
MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

DO-214AB (SMC)



Unit : inch(mm)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)									
PARAMETER	SYMBOL	GS5A	GS5B	GS5D	GS5G	GS5J	GS5K	GS5M	UNIT
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Forward current	$I_{F(AV)}$	5							A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	100							A
Junction temperature	T_J	- 55 to +150							$^\circ\text{C}$
Storage temperature	T_{STG}	- 55 to +150							$^\circ\text{C}$

THERMAL PERFORMANCE

PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance per diode	$R_{\theta JL}$	13	°C/W
Junction-to-ambient thermal resistance per diode	$R_{\theta JA}$	47	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 5\text{A}$, $T_J = 25^\circ\text{C}$	V_F	-	1.15	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	10	μA
	$T_J = 125^\circ\text{C}$		-	250	μA
Junction capacitance	1 MHz, $V_R = 4.0\text{V}$	C_J	60	-	pF
Reverse recovery time	$I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$ $I_{RR} = 0.25\text{A}$	t_{rr}	1500	-	ns

Notes:

1. Pulse test with $PW = 0.3\text{ ms}$
2. Pulse test with $PW = 30\text{ ms}$

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

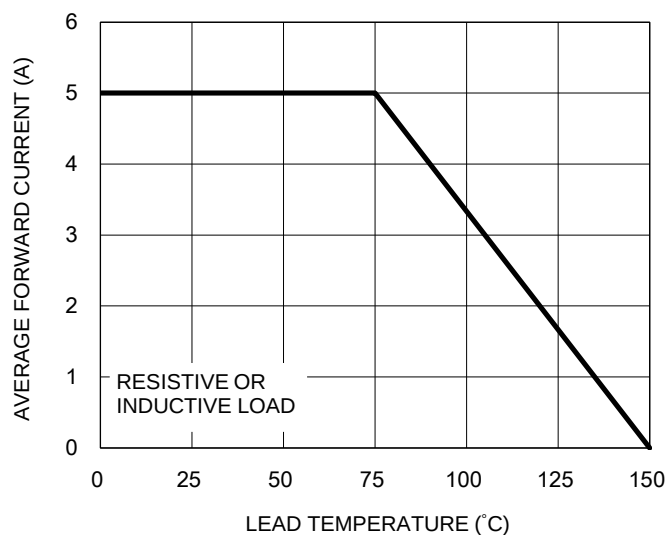


Fig.2 Typical Junction Capacitance

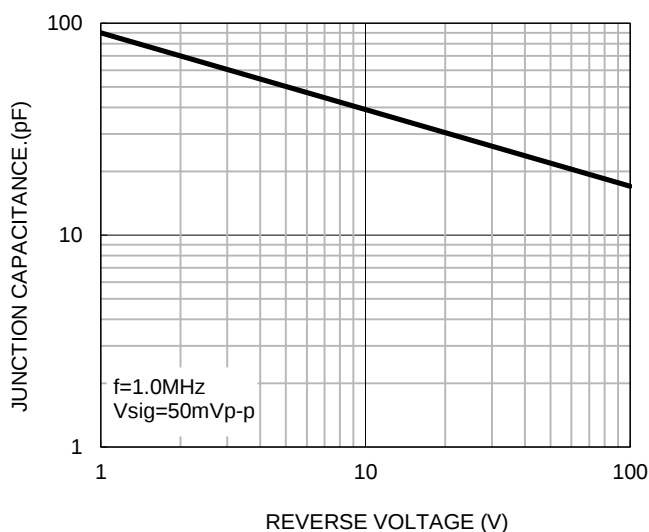


Fig.3 Typical Reverse Characteristics

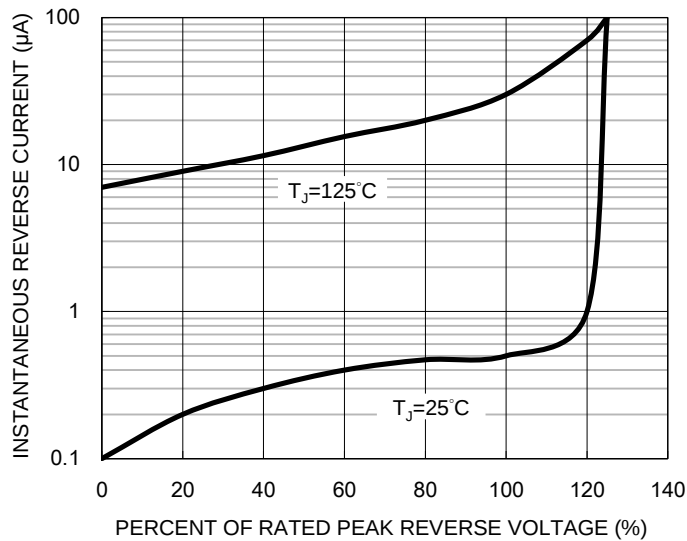


Fig.4 Typical Forward Characteristics

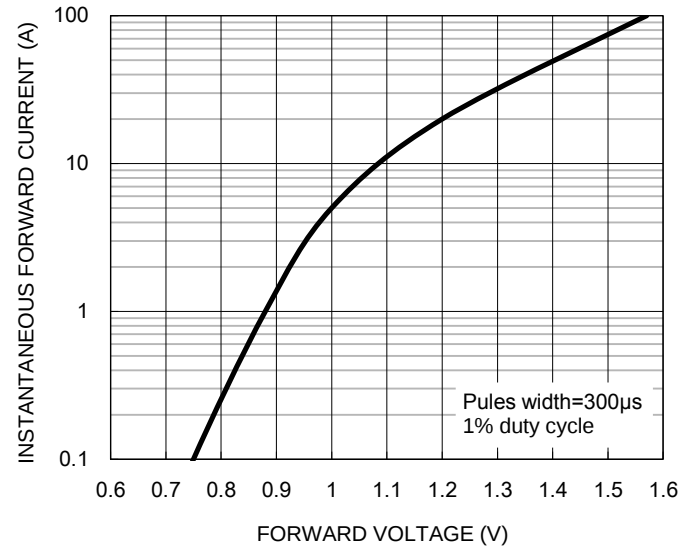


Fig.5 Maximum Non-repetitive Forward Surge Current

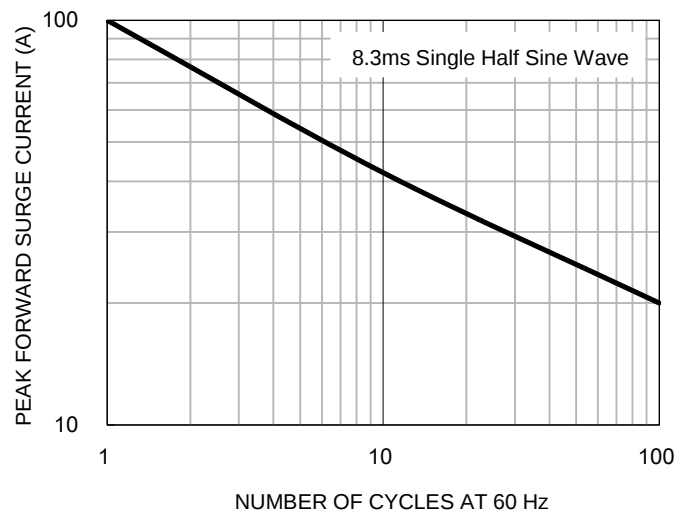


Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram

